

TECHNICAL DATA DATASHEET 4742, REV. B

HERMETIC POWER SCHOTTKY RECTIFIER 175°C Maximum Operation Temperature

DESCRIPTION: A 100-VOLT, 35 AMP, POWER SCHOTTKY RECTIFIER IN A HERMETIC TO-254 PACKAGE.

MAXIMUM RATINGS

ALL RATINGS ARE @ T_C = 25 °C UNLESS OTHERWISE SPECIFIED.

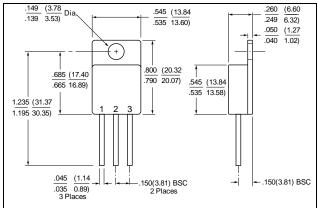
RATING	SYMBOL	MAX.	UNITS
PEAK INVERSE VOLTAGE	PIV	100	Volts
MAXIMUM DC OUTPUT CURRENT (@ T _C =100 °C) (Single)	Io	35	Amps
MAXIMUM NONREPETITIVE FORWARD SURGE CURRENT (t=8.3ms, Sine)		150	Amps
MAXIMUM JUNCTION CAPACITANCE (V _r =5V)	C _T	3000	pF
MAXIMUM THERMAL RESISTANCE (Per leg)	$R_{ heta JC}$	0.62	°C/W
MAXIMUM OPERATING TEMPERATURE RANGE	Top/Tstg	-65 to + 175	°C
MAXIMUM STORAGE TEMPERATURE RANGE	Top/Tstg	-65 to + 175	°C

ELECTRICAL CHARACTERISTICS

CHARACTERISTIC		SYMBOL	MAX.	UNITS
MAXIMUM FORWARD VOLTAGE DROP, Pulsed (I _f = 35 Amps)				
Т	J= 25 °C	V_{f}	0.97	Volts
Т	J= 125 °C		0.79	
MAXIMUM REVERSE CURRENT (Ir @ 100 V PIV)				
	_J = 25 °C	I_r	2	mA
Т	J= 125 °C		48	

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Mechanical Dimensions: In inches / mm







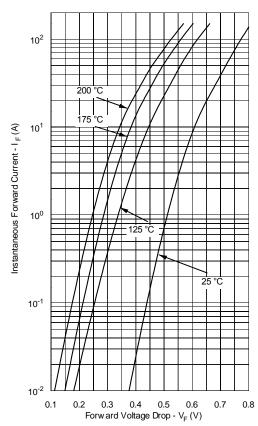
TO-254

PINOUT TABLE

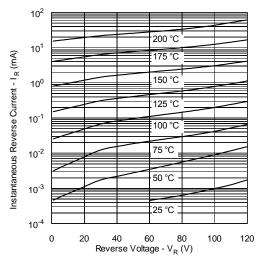
TYPE	PIN 1	PIN 2	PIN 3	ı
SINGLE RECTIFIER	CATHODE	ANODE	ANODE	1

Curves shown are for bare die only.

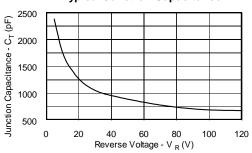
Typical Forward Characteristics



Typical Reverse Characteristics



Typical Junction Capacitance



SENSITRON

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